

	<h2 style="color: red;">SI7942DP-T1-GE3</h2>
 <p>Image may be representation. See specs for product details.</p>	Hersteller-Teilenummer: SI7942DP-T1-GE3
	Hersteller / Marke: Electro-Films (EFI) / Vishay
	Teil der Beschreibung: MOSFET 2N-CH 100V 3.8A PPAK SO-8
	Datenblätter:  SI7942DP-T1-GE3.pdf
	RoHs Status: Bleifrei / RoHS-konform
	Lagerzustand: New original, 2866 pcs Stock Available.
Liefern von: Hong Kong	
Versandweg: DHL/Fedex/TNT/UPS/EMS	

Spezifikationen

Teilenummer	SI7942DP-T1-GE3
Hersteller	Electro-Films (EFI) / Vishay
Beschreibung	MOSFET 2N-CH 100V 3.8A PPAK SO-8
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	2866 pcs Stock
detaillierte Beschreibung	Mosfet Array 2 N-Channel (Dual) 100V 3.8A 1.4W
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	1.4W
Verpackung / Gehäuse	PowerPAK® SO-8 Dual
Supplier Device-Gehäuse	PowerPAK® SO-8 Dual
Typ FET	2 N-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	100V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	3.8A
Rds On (Max) @ Id, Vgs	49 mOhm @ 5.9A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	24nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Cut Tape (CT)
Basisteilenummer	SI7942
Bleifreier Status / RoHS-Status	Lead free / RoHS Compliant
Feuchtigkeitsempfindlichkeitsniveau (MSL)	1 (Unlimited)
Andere Namen	SI7942DP-T1-GE3CT













































SI7942DP-T1-GE3 ist neu im Original, Suche SI7942DP-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI7942DP-T1-GE3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SI7942DP-T1-GE3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI7945DP-T1-E3 Vishay / Siliconix MOSFET 2P-CH 30V 7A PPAK SO-8</p>	 <p>SI7945DP SI SI7945DP SI</p>	 <p>SI7941DP-T1-E3 VISHAY SI7941DP-T1-E3 VISHAY</p>	 <p>SI7942DP VISHAY SI7942DP VISHAY</p>
 <p>SI7945DP-T1-E3 Electro-Films (EFI) / Vishay MOSFET 2P-CH 30V 7A PPAK SO-8</p>	 <p>SI7941DP-T1-GE3 Vishay SI7941DP-T1-GE3 Vishay</p>	 <p>SI7942DP-T1-E3 Electro-Films (EFI) / Vishay MOSFET 2N-CH 100V 3.8A PPAK SO-8</p>	 <p>SI7945DP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2P-CH 30V 7A PPAK SO-8</p>

heiße Teile

Mehr

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|---|---|---|--|---|
|  SI7911DN-T1-E3 |  SI7911DN-T1-GE3 |  SI7911DN-T1-GE3 | D SI7913DN-T1-E3 |  SI7913DN-T1-E3 |
|  SI7913DN-T1-GE3 |  SI7913DN-T1-GE3 | D SI7922DN-T1-E3 |  SI7922DN-T1-E3 |  SI7922DN-T1-GE3 |
|  SI7922DN-T1-GE3 |  SI7923DN-T1-E3 |  SI7923DN-T1-E3 |  SI7923DN-T1-GE3 |  SI7923DN-T1-GE3 |
| D SI7938DP-T1-GE3 |  SI7938DP-T1-GE3 |  SI7940DP |  SI7940DP-T1-E3 |  SI7940DP-T1-E3 |
|  SI7941DP-T1-E3 |  SI7941DP-T1-GE3 |  SI7942DP |  SI7942DP-T1-E3 |  SI7942DP-T1-E3 |
|  SI7942DP-T1-GE3 |  SI7945DP-T1-E3 | D SI7945DP-T1-E3 |  SI7946DP |  SI7946DP-T1-E3 |
|  SI7946DP-T1-E3 | D SI7948DP |  SI7948DP-T1-E3 |  SI7949DP-T1-GE3 |  SI7949DP-T1-GE3 |
|  SI7956DP-T1-GE3 |  SI7956DP-T1-GE3 |  SI7958DP |  SI7958DP-T1-E3 |  SI7958DP-T1-E3 |
|  SI7958DP-T1-GE3 |  SI7958DP-T1-GE3 |  SI7960DP-T1-E3 | D SI7960DP-T1-E3 |  SI7960DP-T1-GE3 |
|  SI7960DP-T1-GE3 |  SI7964DP |  SI7964DP-T1-GE3 |  SI7964DP-T1-GE3 |  SI7970DP |

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